R1-14

ΣΔ-Modulator with High Nearby Interferers Suppression by Transmission Zeroes

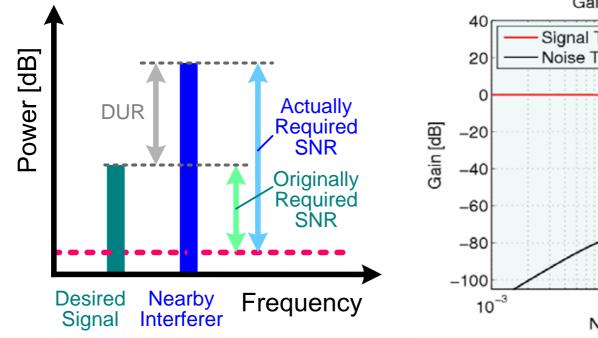
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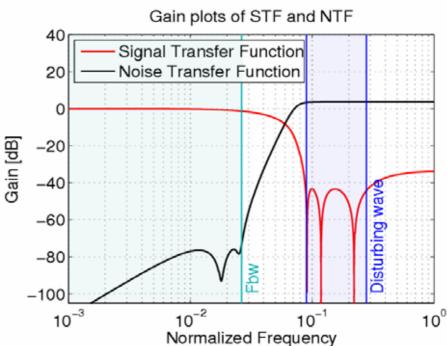
Back Ground

- ◆In receivers of some wireless standards, higher resolution (and DR) ADC is required because of large nearby interferer.
- Large interferer also causes serious instability.

• Proposed $\Sigma\Delta$ -Modulator

- Notched Signal-Transfer-Function realized by feedforward signal passes suppresses nearby interferers.
- ◆Equivalent SQNR (and DR) for nearby interferer is increased.



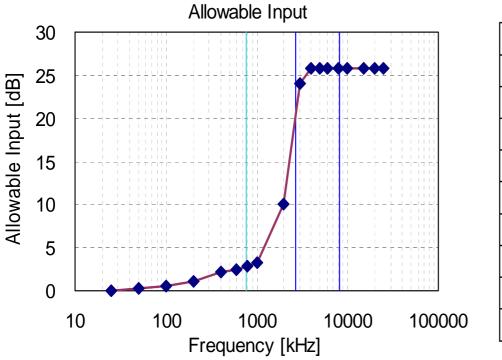


◆Influence of Noise

•In thermal noise dominated $\Sigma\Delta$ -modulator, the effect of DR increase is lowered because of limited input signal amplitude and noise.

Implementation

- •A 777kHz-BW DT 6th-order $\Sigma\Delta$ -modulator has been Implemented in 0.18um CMOS technology.
- More than 20 dB suppression of nearby interferers have been measured.



| Input Sampling Frequency | 59.0625 MHz |
|----------------------------|----------------------|
| Band Width | 777 kHz |
| Interferer Frequency Range | 2.65 MHz - 8.22 MHz |
| Interferer Suppression | 20 dB+ |
| Supply Voltage | 1.8 V |
| CMOS Process | $0.18~\mu\mathrm{m}$ |
| Peak SNR (Designed) | 70 dB+ |
| Peak SNR (Measured) | 59 dB |
| Power Consumption | 45.5 mW |
| Core Size | 0.94 mm^2 |
| | |